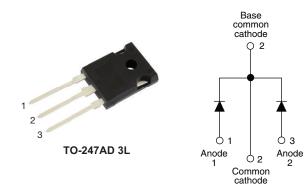
VS-C4PU3006LHN3

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Ultrafast Soft Recovery Diode, 2 x 15 A FRED Pt[®] Gen 4



PRODUCT SUMMARY						
Package	TO-247AD 3L					
I _{F(AV)}	2 x 15 A					
V _R	600 V					
V _F at I _F	1.12 V					
t _{rr} typ.	See Recovery table					
T _J max.	175 °C					
Diode variation	Single die					

FEATURES

- Gen 4 FRED Pt[®] technology
- Low I_{BBM} and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- FREE AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow $V_{\text{F}},$ soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 146 °C	15	^				
Non-repetitive peak surge current, per leg	I _{FSM}	T_C = 25 °C, t_p = 8.3 ms, half sine wave	200	A				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)								
PARAMETER	R SYMBOL		MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-			
		I _F = 15 A	-	1.32	1.55			
	V _F	I _F = 30 A	-	1.53	-	v		
Forward voltage		I _F = 15 A, T _J = 125 °C	-	1.17	-			
Forward voltage		I _F = 30 A, T _J = 125 °C	-	1.42	-			
		I _F = 15 A, T _J = 150 °C	-	1.12	1.28			
		I _F = 30 A, T _J = 150 °C	-	1.38	-			
	I _R	$V_{R} = V_{R}$ rated	-	-	15			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V _R = 600 V	-	16	-	pF		



RoHS COMPLIANT HALOGEN

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
Poweros rosovon timo	+	T _J = 25 °C		-	60	-	20	
Reverse recovery time	t _{rr}	T _J = 125 °C	1 15 4	-	83	-	ns	
Peak recovery current		T _J = 25 °C	l _F = 15 A dl _F /dt = 1000 A/µs	-	13	-	А	
Feat recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm B} = 400 \text{ V}$	-	21	-		
Poverse receivery charge	Q _{rr}	T _J = 25 °C	vR = 400 v	-	500	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1100	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R _{thJC}		-	-	1.4	°C/W		
Thermal resistance, case to heat sink	R _{thCS}		-	0.4	-			
Weight			-	6.0	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0	_	12	kgf · cm		
			(5)	-	(10)	$(lbf \cdot in)$		
Marking device		Case style TO-247AD 3L	C4PU3006LH					

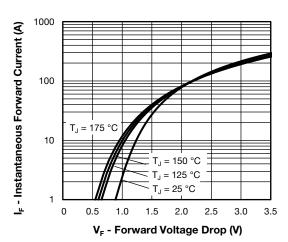


Fig. 1 - Typical Forward Voltage Drop Characteristics

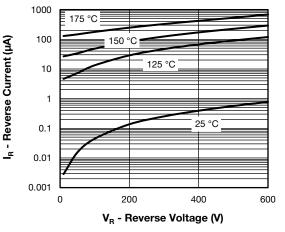


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

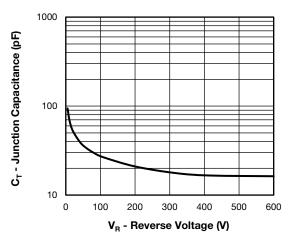
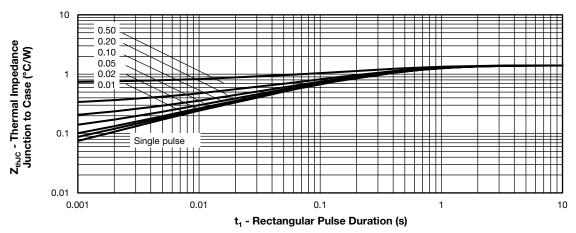


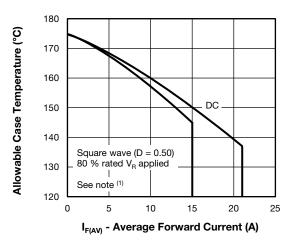
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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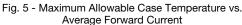
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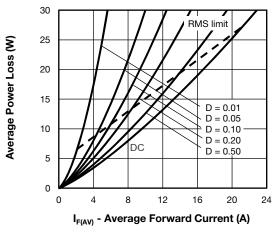


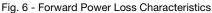




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Note

⁽¹⁾ Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/D) \mbox{ (see Fig.5)} \\ \mbox{P}_{dREV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R} = \mbox{rated } \mbox{V}_{R} \end{array}$

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140 130 120 110 125 °C 100 \mathbf{t}_{rr} (ns) 90 25 °C 80 70 60 50 400 700 1000 500 600 800 900 dl_F/dt (A/µs)



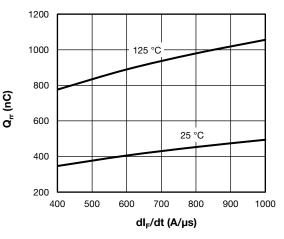


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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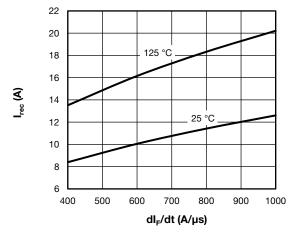


Fig. 9 - Typical Reverse Current vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code	VS-	С	4	Р	U	30	06	L	н	N3
	1	2	3	4	5	6	7	8	9	10
	1 - 2 - 3 - 4 - 5 -	Circ C = FRE P = Pro	commo ED Pt G TO-247 cess typ	packag	n: Je	oduct				
	6 - 7 - 8 - 9 - 10 -	Cur Volt Pac H = Env	rent rati age rati kage: L AEC-Q ironmer	ng (30 = ng (06 = = long l 101 qua tal digit: en-free,	= 2 x 15 = 600 V) ead lified		nt, and t	otally le	ad (Pb)	-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-C4PU3006LHN3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626			
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007			

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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	254	0.0	010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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